P-Channel 40-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- Fast switching speed

Typical Applications:

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY				
VDS (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)		
-40	4.2 @ V _{GS} = -10V	-110 ^a		
-40	6 @ V _{GS} = -4.5V	-110		

20





D Top View

G

S

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)							
Parameter			Limit	Units			
Drain-Source Voltage			-40	V			
Gate-Source Voltage		V _{GS}	±20	v			
Continuous Drain Current ^a	T _C =25°C	I _D	-110	А			
Pulsed Drain Current ^b		I _{DM}	-400	A			
Continuous Source Current (Diode Conduction) ^a	T _C =25°C	۱ _s	-110	А			
Power Dissipation ^a	T _C =25°C	PD	300	W			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C			

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
Maximum Junction-to-Ambient °	R _{θJA}	62.5	°C/W			
Maximum Junction-to-Case	R _{θJC}	0.5	0/11			

Notes

- Package Limited a.
- Pulse width limited by maximum junction temperature b.
- Surface Mounted on 1" x 1" FR4 Board. c.

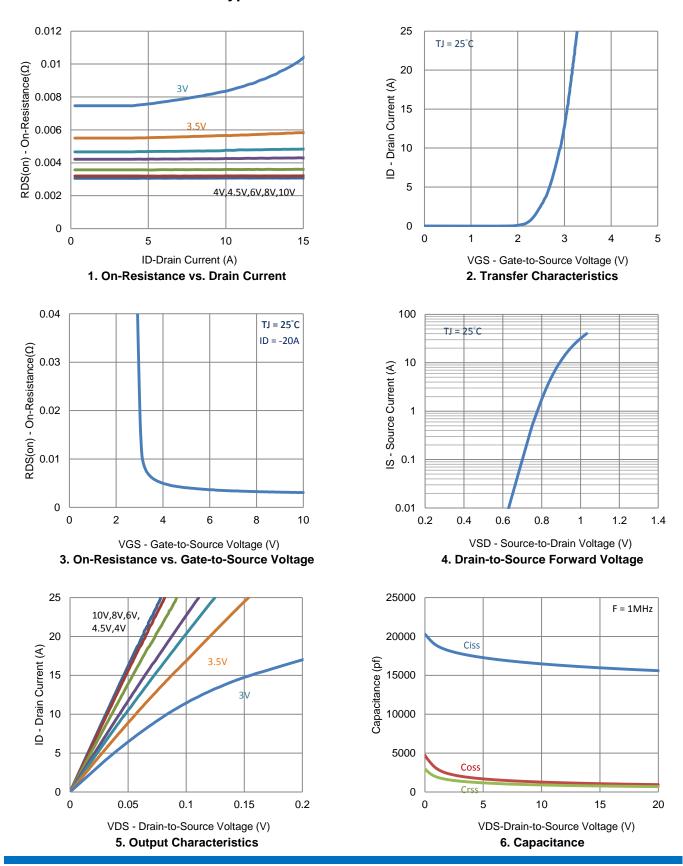
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Static								
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-1			V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA		
Zero Gate Voltage Drain Current		$V_{DS} = -32 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			-1	uA		
	I _{DSS}	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10	uA		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	-150			А		
Drain Source On Desistence ^a	r _{no} ,	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -20 \text{ A}$			4.2 mΩ			
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -16 \text{ A}$			6	11122		
Forward Transconductance ^a	g _{fs}	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -20 \text{ A}$		26		S		
Diode Forward Voltage ^a	V_{SD}	$I_{S} = -55 \text{ A}, V_{GS} = 0 \text{ V}$		0.75		V		
		Dynamic ^b						
Total Gate Charge	Qg	V = -20 V V = -4 5 V		118				
Gate-Source Charge	Q _{gs}	$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = -4.5 \text{ V},$ $I_{D} = -20 \text{ A}$		43		nC		
Gate-Drain Charge	Q_{gd}	10 - 20 77		44				
Turn-On Delay Time	t _{d(on)}	$V_{DS} = -20 \text{ V}, \text{ R}_{L} = 1 \Omega,$		33				
Rise Time	t _r	$V_{DS} = -20 \text{ V}, \text{ K}_{L} = -1 \Omega_{2},$ $I_{D} = -20 \text{ A},$		99		ns		
Turn-Off Delay Time	t _{d(off)}	$V_{\text{GEN}} = -10 \text{ V}, \text{ R}_{\text{GEN}} = 6 \Omega$		387				
Fall Time	t _f	$v_{\text{GEN}} = 10$ v_{S} $n_{\text{GEN}} = 0.22$		140				
Input Capacitance	C _{iss}			15963				
Output Capacitance	C _{oss}	V_{DS} = -15 V, V_{GS} = 0 V, f = 1 Mhz		1067		pF		
Reverse Transfer Capacitance	C _{rss}			767				

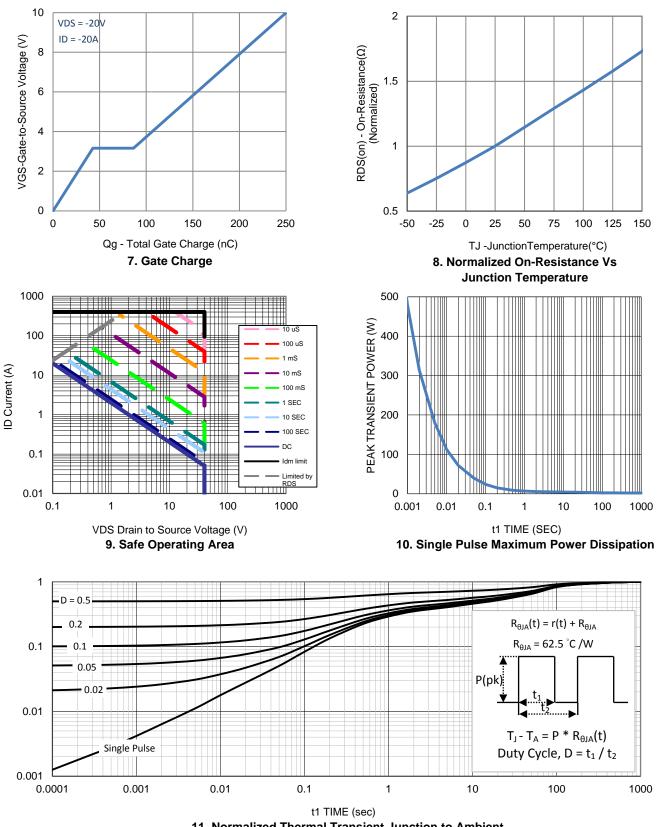
Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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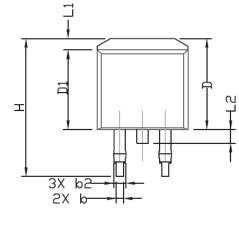
Typical Electrical Characteristics

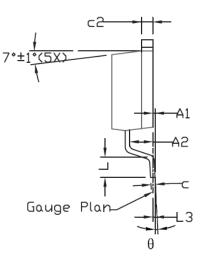


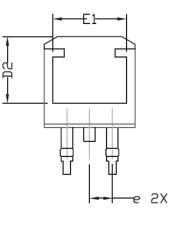
Typical Electrical Characteristics

11. Normalized Thermal Transient Junction to Ambient

Package Information







	DIMENS	IONAL F	REQMTS	INCH	ES REG	MTS		
SYMBOL	MIN	NDM	MAX	MIN	NDM	MAX		
A	4,30	4.57	4,72	0.169	0.180	0.186		
A1	0		0.25	0		0.010		
A2	2,47	2,57	2,67	0,097	0.101	0.105		
ø	0.69	0.813	0.94	0.027	0.032	0.037		
b2	1.17	1.27	1,45	0.046	0.050	0.057		
С	0.48	0,50	0.60	0.019	0.020	0.024		
c2	1,17	1.27	<u>1.37</u>	0.046	0.050	0.054		
Ď	9,80	10.05	10.30	0.386	0,396	0.406		
D1	8,64	8.78	9,65	0,340	0.346	0.380		
D2	7,12	7.37	7,62	0.280	0.290	0.300		
E	9,70	10.15	10.54	0,382	0.400	0.415		
E1	8,00	8,20	8,40	0,315	0,323	0.331		
e	2,54 BSC			0.3	0.100 BSC			
Н	14.99	15.24	15.49	0.590	0.600	0.610		
L	1.78	2,29	2,79	0.070	0.090	0.110		
L1	1.02	1.27	1.52	0.040	0.050	0.060		
L2			1.75			0.069		
L3		0,254			0.010			
θ	0*		8*	0*		8*		